

| IN THE UNITED STATES PATENT AND TRADEMARK OFFICE | | | |
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| PEC | | ੜ | ±11/AmathB |
| In re Patent Application of: |) | Group Art Unit: 2814 | a/1=/2 |
| Ritsuko KAWASAKI et al. (SE 05 2002 gi) |) | Examiner: D. Farahani | |
| Serial No. 09/651,889 |) | | E C. Harri |
| Filed: August 30, 2000 |) | | SEP -S |
| For: SEMICONDUCTOR DEVICE, |) | | P- |
| MANUFACTURING METHOD |) | | |
| THEREOF AND ELECTRONIC |) | | VED 2002 CENTER |
| DEVICE |) | | 280 |
| • | | | 0 |

AMENDMENT

Commissioner of Patents Washington, D.C. 20231

Dear Sir:

In response to the Examiner's non-final Office Action dated June 6, 2002, please amend the above-identified application as follows.

IN THE CLAIMS:

Please amend claims 1-3 and 11-16 as follows. The amendments to the claims are outlined in an Attachment to the Amendment using the conventional indication method of bracketing and underlining.

BOO

1. (Twice Amended) A semiconductor device comprising a TFT containing an active layer having a channel forming region,

wherein the channel forming region has a convex portion or a concave portion extending in a channel width direction.